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View Online at https://aerobasegroup.com/nsn/5961-01-281-5026

Inclosure Material:	
Metal	
Overall Length:	
1.450 inches	
Function For Which Designed:	
Voltage regulator	
Mounting Facility Quantity:	
1	
Electrode Internally-electrically Connected To Case:	
Anode	
Mounting Method:	
Threaded stud	
Thread Size:	
0.250 inches	
Criticality Code Justification:	
Zzzy	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
16.0 regulator voltage	
Voltage Tolerance In Percent:	
-1.0/+1.0	
Current Rating Per Characteristic:	
780.00 milliamperes all primaries horsepower metric	
Power Rating Per Characteristic:	
50.0 watts small-signal input power, common-collector absolute	
Maximum Operating Tempurature Per Measurement Point:	
125.0 degrees celsius ambient air	
Special Features:	
Item must comply with requirements of defense supply center columbus production standard no. Lo40	04
Thread Series Designator:	
Unf	
Terminal Type And Quantity:	
1 tab, solder lug and 1 threaded stud	

Reference Number Differentiating Characteristics:

Breference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing

and testing specifications available at the dla icp.

Shelf Life:

N/a

Unit Of Measure:

- ---
- Demilitarization:
- Yes demil/mli

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